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- State-of-the-Art Advanced BiCMOS Technology (ABT) *Widebus*<sup>™</sup> Design for 2.5-V and 3.3-V Operation and Low Static Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V<sub>CC</sub>)
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> =  $25^{\circ}$ C
- Power Off Disables Outputs, Permitting Live Insertion
- High-Impedance State During Power Up and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Output Ports Have Equivalent 30-Ω Series Resistors, So No External Resistors Are Required
- Auto3-State Eliminates Bus Current Loading When Output Exceeds V<sub>CC</sub> + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V Using Charged-Device Model, Robotic Method
- Flow-Through Architecture Facilitates Printed Circuit Board Layout
- Distributed V<sub>CC</sub> and GND Pin Configuration Minimizes High-Speed Switching Noise
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

NOTE: For order entry: The DGG package is abbreviated to G, and the DGV package is abbreviated to V.

### description

The 'ALVTH162244 devices are 16-bit buffers/line drivers designed for low-voltage 2.5-V or 3.3-V  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.



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SN54ALVTH162244 WD PACKAGE
SN74ALVTH162244 DGG, DGV, OR DL PACKAGE
(TOP VIEW)

(	TOP VIE	EW)	
( 10E 1Y1 1Y2 GND 1Y3 1Y4 V <sub>CC</sub> QND 2Y2 GND 2Y2 QND 2Y3 2Y4 3Y1	1 2 3 4 5 6 7 8 9 10 11 12 13	48 47 46 45 44 43 42 41 40 39 38 37 36	20E 1A1 1A2 GND 1A3 1A4 Vcc 2A1 2A2 GND 2A3 2A4 3A1
GND	15	34	GND
3Y3	16	33	3A3
3Y4 [	17	32	] 3A4
V <sub>CC</sub> [	18	31	] V <sub>CC</sub>
4Y1 [	19	30	] 4A1
4Y2 [	20	29	] 4A2
GND [	21	28	] GND
4Y3	22	27	4A3
4Y4	23	26	4A4
4OE	24	25	3OE

### SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCES074E – JUNE 1996 - REVISED JANUARY 1999

description (continued)

These devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. These devices provide true outputs and symmetrical active-low output-enable ( $\overline{OE}$ ) inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

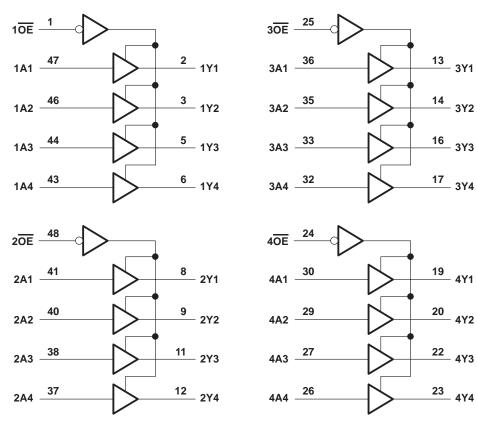
When  $V_{CC}$  is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

All outputs are designed to sink up to 12 mA and include equivalent  $30-\Omega$  resistors to reduce overshoot and undershoot.

The SN54ALVTH162244 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ALVTH162244 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 4-bit buffer)										
INP	JTS	OUTPUT								
OE	Α	Y								
L	Н	Н								
L	L	L								
Н	Х	Z								

### logic diagram (positive logic)





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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V_CC $\ldots \ldots $
Input voltage range, V <sub>I</sub> (see Note 1) –0.5 V to 7 V
Voltage range applied to any output in the high-impedance
or power-off state, V <sub>O</sub> (see Note 1)
Voltage range applied to any output in the high state, V <sub>O</sub> (see Note 1) –0.5 V to 7 V
Output current in the low state, I <sub>O</sub>
Output current in the high state, I <sub>O</sub>
Input clamp current, $I_{IK}$ (V <sub>I</sub> < 0) -50 mA
Output clamp current, $I_{OK}$ (V <sub>O</sub> < 0)
Package thermal impedance, $\theta_{JA}$ (see Note 2): DGG package
DGV package
DL package
Storage temperature range, T <sub>stg</sub>

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

## recommended operating conditions, V<sub>CC</sub> = 2.5 V $\pm$ 0.2 V (see Note 3)

			SN54A	LVTH16	62244	SN74A	LVTH16	2244	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage	bly voltage				2.3		2.7	V
VIH	High-level input voltage	1.7		h	1.7			V	
VIL	Low-level input voltage		Vin.	0.7			0.7	V	
VI	Input voltage	0	Vcc	5.5	0	VCC	5.5	V	
ЮН	High-level output current			1	-6			-8	mA
IOL	Low-level output current			22	8			12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	20,	5	10			10	ns/V
Δt/ΔV <sub>CC</sub>	Power-up ramp rate		200			200			μs/V
ТА	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## recommended operating conditions, V<sub>CC</sub> = 3.3 V $\pm$ 0.3 V (see Note 3)

							LVTH16	62244	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VCC	Supply voltage		3		3.6	3		3.6	V
VIH	High-level input voltage	2		W.	2			V	
VIL	Low-level input voltage		ľu,	0.8			0.8	V	
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
ЮН	High-level output current			1	-8			-12	mA
IOL	Low-level output current			22	8			12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		5	10			10	ns/V
Δt/ΔVCC	Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature	-55		125	-40		85	°C	

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (unless otherwise noted)

D.	ARAMETER	TEST CO		SN54A	LVTH1	62244	SN74/	ALVTH16	62244	UNIT	
Ρ/	ARAMETER	TEST CO	NDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNII	
VIK		V <sub>CC</sub> = 2.3 V,	lj = -18 mA			-1.2			-1.2	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V,	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0.2	2		V <sub>CC</sub> -0.	.2			
∨он			I <sub>OH</sub> = -6 mA	1.7						V	
		$V_{CC} = 2.3 V$	IOH = -8 mA				1.7				
		$V_{CC}$ = 2.3 V to 2.7 V,	I <sub>OL</sub> = 100 μA			0.2			0.2		
VOL		V <sub>CC</sub> = 2.3 V	I <sub>OL</sub> = 8 mA			0.7				V	
		VCC = 2.3 V	I <sub>OL</sub> = 12 mA						0.7		
	Control	V <sub>CC</sub> = 2.7 V,	$V_I = V_{CC} \text{ or } GND$			±1			±1		
	inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	VI = 5.5 V			10			10		
lj –			V <sub>I</sub> = 5.5 V			10			10	μA	
	Data inputs	V <sub>CC</sub> = 2.7 V	$V_I = V_{CC}$			3 1			1		
		$V_{I} = 0$			-5			-5			
loff		$V_{CC} = 0,$	$V_{I}$ or $V_{O}$ = 0 to 4.5 V		7				±100	μA	
I <sub>BHL</sub> ‡	ŧ	V <sub>CC</sub> = 2.3 V,	V <sub>I</sub> = 0.7 V		115			115		μA	
IBHH		V <sub>CC</sub> = 2.3 V,	V <sub>I</sub> = 1.7 V		5-10			-10		μΑ	
BHLO	o¶	V <sub>CC</sub> = 2.7 V,	$V_I = 0$ to $V_{CC}$	300	5		300			μA	
IBHH	0 <sup>#</sup>	V <sub>CC</sub> = 2.7 V,	$V_I = 0$ to $V_{CC}$	-300			-300			μA	
IEX		V <sub>CC</sub> = 2.3 V,	V <sub>O</sub> = 5.5 V			125			125	μA	
IOZ(F	PU/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_O = 0.5 \text{ V} \text{ to}$ $V_I = \text{GND or } V_{CC}, \overline{\text{OE}} = \text{dot}$	o V <sub>CC</sub> , on't care			±100			±100	μΑ	
IOZH		V <sub>CC</sub> = 2.7 V	V <sub>O</sub> = 2.3 V, V <sub>I</sub> = 0.7 V or 1.7 V			5			5	μA	
I <sub>OZL</sub>		V <sub>CC</sub> = 2.7 V	V <sub>O</sub> = 0.5 V, V <sub>I</sub> = 0.7 V or 1.7 V			-5			-5	μA	
		V <sub>CC</sub> = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1		
ICC	$I_{O} = 0,$	Outputs low		2.3	4.5		2.3	4.5	mA		
		$V_{I} = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V <sub>CC</sub> = 2.5 V,	V <sub>I</sub> = 2.5 V or 0		3			3		pF	
Co		V <sub>CC</sub> = 2.5 V,	V <sub>O</sub> = 2.5 V or 0		6			6		pF	

<sup>†</sup> All typical values are at  $V_{CC} = 2.5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>‡</sup> The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

S The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

 $\P$  An external driver must source at least  $I_{BHLO}$  to switch this node from low to high.

# An external driver must sink at least IBHHO to switch this node from high to low.

I Current into an output in the high state when  $V_{O} > V_{CC}$ 

\*High-impedance state during power up or power down



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# electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted)

DA	RAMETER	TEST O		SN54A	LVTH1	62244	SN74/	ALVTH16	62244	UNIT	
FA	RANEIER	TEST CO	ONDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK		$V_{CC} = 3 V,$	lı = –18 mA			-1.2			-1.2	V	
		V <sub>CC</sub> = 3 V to 3.6 V,	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> -0.	2		V <sub>CC</sub> -0	.2			
∨он			I <sub>OH</sub> = -8 mA	2							
		V <sub>CC</sub> = 3 V	$I_{OH} = -12 \text{ mA}$				2				
		V <sub>CC</sub> = 3 V to 3.6 V,	I <sub>OL</sub> = 100 μA			0.2			0.2		
Vol			IOL = 8 mA	0.8						V	
		V <sub>CC</sub> = 3 V	I <sub>OL</sub> = 12 mA						0.8		
	Control	V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC} \text{ or } GND$			±1			±1		
	inputs	V <sub>CC</sub> = 0 or 3.6 V	Vj = 5.5 V			10			10		
lj –			V <sub>I</sub> = 5.5 V			10			10	μA	
	Data inputs	V <sub>CC</sub> = 3.6 V	$V_{I} = V_{CC}$			3 1					
			VI = 0		1	5			-5		
l <sub>off</sub>		$V_{CC} = 0,$	$V_{I}$ or $V_{O}$ = 0 to 4.5 V		24				±100	μA	
I <sub>BHL</sub> ‡		V <sub>CC</sub> = 3 V,	V <sub>I</sub> = 0.8 V	75	5		75			μA	
I <sub>BHH</sub> §	3	$V_{CC} = 3 V,$	V <sub>I</sub> = 2 V	-75	2		-75			μA	
BHLC	P	V <sub>CC</sub> = 3.6 V,	$V_I = 0$ to $V_{CC}$	500	5		500			μA	
Івнно	D <sup>#</sup>	V <sub>CC</sub> = 3.6 V,	$V_I = 0$ to $V_{CC}$	-500			-500			μA	
IEX		V <sub>CC</sub> = 3 V,	V <sub>O</sub> = 5.5 V			125			125	μA	
IOZ(P	U/PD)☆	$V_{CC} \le 1.2 \text{ V}, \text{ V}_{O} = 0.5 \text{ V}$ VI = GND or V <sub>CC</sub> , OE = 0	to V <sub>CC</sub> , don't care			±100			±100	μΑ	
I <sub>OZH</sub>		V <sub>CC</sub> = 3.6 V	V <sub>O</sub> = 3 V, V <sub>I</sub> = 0.8 V or 2 V			5			5	μΑ	
I <sub>OZL</sub>		V <sub>CC</sub> = 3.6 V	V <sub>O</sub> = 0.5 V, V <sub>I</sub> = 0.8 V or 2 V			-5			-5	μA	
		V <sub>CC</sub> = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1		
ICC	$I_{O} = 0,$	Outputs low		3.2	5		3.2	5	mA		
		$V_I = V_{CC}$ or GND	Outputs disabled		0.07	0.1		0.07	0.1		
$\Delta I_{CC} \square \qquad $					0.4			0.4	mA		
Ci		V <sub>CC</sub> = 3.3 V,	V <sub>I</sub> = 3.3 V or 0		3			3		pF	
Co		V <sub>CC</sub> = 3.3 V,	V <sub>O</sub> = 3.3 V or 0		6			6		pF	

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> =  $25^{\circ}$ C.

<sup>‡</sup> The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

§ The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

 $\P$  An external driver must source at least I<sub>BHLO</sub> to switch this node from low to high.

<sup>#</sup> An external driver must sink at least I<sub>BHHO</sub> to switch this node from high to low.

I Current into an output in the high state when  $V_O > V_{CC}$ 

\*High-impedance state during power up or power down

□ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.



## SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCES074E - JUNE 1996 - REVISED JANUARY 1999

switching characteristics over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF, V<sub>CC</sub> = 2.5 V  $\pm$  0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALVTH	1162244	SN74ALVTH	1162244	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
<sup>t</sup> PLH	А	v	1	4.3	1	4.2	ns
<sup>t</sup> PHL	~		1.4	3.8	1.5	3.7	115
<sup>t</sup> PZH	OE	v	1.3	6.9	1.4	6.8	ns
<sup>t</sup> PZL	UE		1.3	5.2	1.4	5.1	115
<sup>t</sup> PHZ	OE	V	0	4.7	1	4.6	ns
<sup>t</sup> PLZ	UE		\$ 1	3.6	1	3.5	115

switching characteristics over recommended operating free-air temperature range, CL = 50 pF, V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVTH1	62244	SN74ALVTH	1162244	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT	
<sup>t</sup> PLH	٨	V	1	3.4	1	3.3	200	
<sup>t</sup> PHL	А	T	1	3.4	1	3.3	ns	
<sup>t</sup> PZH	ŌĒ	V	1.4	5	1.5	4.9	ns	
<sup>t</sup> PZL	OE	T	1.3	3.4	1.4	3.3	115	
<sup>t</sup> PHZ	ŌĒ	V	1.4	5	1.5	4.9	ns	
<sup>t</sup> PLZ	ÛE	I	<b>2</b> 1.4	4.4	1.5	4.3	115	



#### SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCES074E – JUNE 1996 - REVISED JANUARY 1999

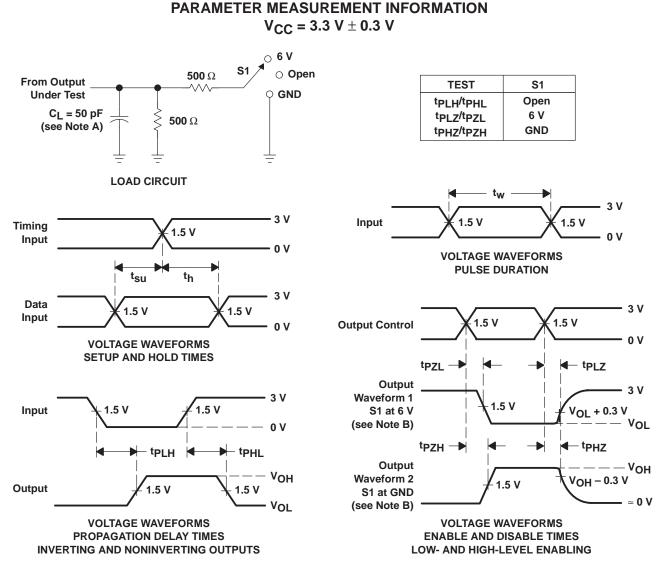
PARAMETER MEASUREMENT INFORMATION  $V_{CC} = 2.5 V \pm 0.2 V$  $\odot 2 \times V_{CC}$ **S1** O Open **500** Ω **From Output** TEST **S1**  $\wedge \wedge \wedge$ O GND **Under Test** Open tPLH/tPHL  $C_L = 30 \text{ pF}$  $2 \times V_{CC}$ <sup>t</sup>PLZ<sup>/t</sup>PZL **500** Ω (see Note A) GND tPHZ/tPZH LOAD CIRCUIT tw Vcc Vcc Input V<sub>CC</sub>/2 V<sub>CC</sub>/2 Timing V<sub>CC</sub>/2 0 V Input 0 V **VOLTAGE WAVEFORMS** PULSE DURATION t<sub>su</sub> t<sub>h</sub> Vcc Output Data Vcc V<sub>CC</sub>/2 V<sub>CC</sub>/2 Control Input V<sub>CC</sub>/2 V<sub>CC</sub>/2 (low-level 0 V 0 V enabling) **VOLTAGE WAVEFORMS** SETUP AND HOLD TIMES - tplz tp7I Output Vcc Vcc Waveform 1 V<sub>CC</sub>/2 V<sub>CC</sub>/2 S1 at  $2 \times V_{CC}$ Input V<sub>CC</sub>/2 V<sub>OL</sub> + 0.15 V (see Note B) 0 V Vol <sup>t</sup>PZH <sup>t</sup>PHZ <sup>t</sup>PHL **t**PLH Output – Vон VOH Waveform 2 V<sub>OH</sub> – 0.15 V V<sub>CC</sub>/2 Output V<sub>CC</sub>/2 V<sub>CC</sub>/2 S1 at GND 0 V VOL (see Note B) **VOLTAGE WAVEFORMS VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES ENABLE AND DISABLE TIMES** 

- NOTES: A. CL includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2 ns, t<sub>f</sub>  $\leq$  2 ns.
  - D. The outputs are measured one at a time with one transition per measurement.

#### Figure 1. Load Circuit and Voltage Waveforms



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NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform22 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.

D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms



## PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74ALVTH162244DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH162244GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH162244GRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH162244LRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH162244VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH162244VRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH162244DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH162244GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH162244LR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH162244VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

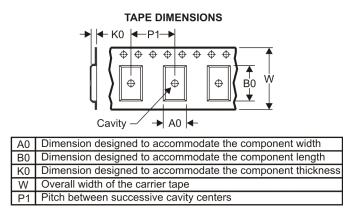
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# TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

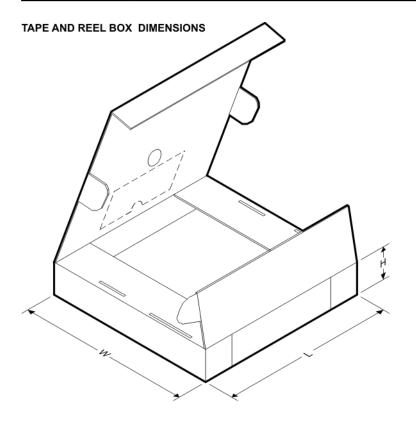


*All dimensions are nominal	Il dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant	
SN74ALVTH162244GR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1	
SN74ALVTH162244LR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1	
SN74ALVTH162244VR	TVSOP	DGV	48	2000	330.0	24.4	6.8	10.1	1.6	12.0	24.0	Q1	



# PACKAGE MATERIALS INFORMATION

11-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVTH162244GR	TSSOP	DGG	48	2000	346.0	346.0	41.0
SN74ALVTH162244LR	SSOP	DL	48	1000	346.0	346.0	49.0
SN74ALVTH162244VR	TVSOP	DGV	48	2000	346.0	346.0	41.0

# **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

### DGG (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



# **MECHANICAL DATA**

MSSO001C - JANUARY 1995 - REVISED DECEMBER 2001

#### PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN

DL (R-PDSO-G\*\*)



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118



# **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

## DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



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